

## NTLUD3A260PZTAG

Data Sheet

IGBT Transistors POWER MOSFET 20V 2A 200 M

Manufacturers ON Semiconductor, LLC

Package/Case UDFN-6

Product Type Transistors

RoHS Rohs

Lifecycle



Images are for reference only

Please submit RFQ for NTLUD3A260PZTAG or Email to us: sales@ovaga.com We will contact you in 12 hours.



## **General Description**

Power MOSFET-20 V, -2.1 A, µCoolTM Dual P-Channel, ESD, 1.6x1.6x0.55 mm UDFN Package

**Features** Application

UDFN Package with Exposed Drain Pads

**Excellent Thermal Conduction** 

Low Profile UDFN 1.6x1.6x0.55 mm

Board Space Saving, Thin Designs

**ESD Protected Gate** 

Improved Ruggedness, Increased Reliability

RoHS Compliant

## **Related Products**



NTR4003NT3G
ON Semiconductor, LLC
SOT-23



NTD2955G
ON Semiconductor, LLC
TO-252

**ONSEMI** 



NTZD3155CT2G

ON Semiconductor, LLC SOT-563-6



**NTR5103NT1G** 

ON Semiconductor, LLC SOT-23



**NTHD4102PT1G** 

ON Semiconductor, LLC ChipFET-8



**NTS2101PT1G** 

ON Semiconductor, LLC SOT-323



NTMFS4C10NT1G

ON Semiconductor, LLC SO-8FL



NTH4L020N120SC1

ON Semiconductor, LLC TO-247